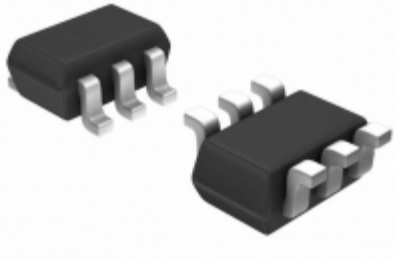








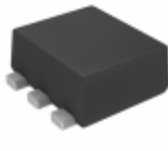

	<h2 style="color: #e67e22;">US6J11TR</h2>	
	<b>Manufacturer Part Number:</b>	<a href="#">US6J11TR</a>
	<b>Manufacturer/Brand:</b>	<a href="#">LAPIS Semiconductor</a>
	<b>Part of Description:</b>	MOSFET 2P-CH 12V 1.3A TUMT6
<b>Datasheets:</b>	 <a href="#">US6J11TR.pdf</a>	
<b>RoHs Status:</b>	 Lead free / RoHS Compliant	
<b>Stock Condition:</b>	New original, 1977 pcs Stock Available.	
<b>Ship From:</b>	Hong Kong	
<b>Shipment Way:</b>	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

### Specifications

Part Number	US6J11TR
Manufacturer	LAPIS Semiconductor
Description	MOSFET 2P-CH 12V 1.3A TUMT6
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	1977 pcs Stock
Series	-
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Power - Max	320mW
Package / Case	6-TSSOP, SC-88, SOT-363
Supplier Device Package	UMT6
FET Type	2 P-Channel (Dual)
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	12V
Current - Continuous Drain (Id) @ 25°C	1.3A
Rds On (Max) @ Id, Vgs	260 mOhm @ 1.3A, 4.5V
Vgs(th) (Max) @ Id	1V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	2.4nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	290pF @ 6V
Packaging	Tape & Reel (TR)

US6J11TR is New Original in Stock, Search US6J11TR Datasheets, PDF, Inventory at Y-IC.com Online, Order US6J11TR LAPIS Semiconductor with warrantied and confidence. RFQ US6J11TR : Info@Y-IC.com

### You May Be Also Be interested In:

 <p><b>US681-C00005-500PG</b> Agastat Relays / TE Connectivity SENSOR 500PSIG 1/4NPT 4-20MA 2'</p>	 <p><b>US6J12</b> LAPIS Semiconductor US6J12 ROHM</p>	 <p><b>US6J2PAK</b> Hamlin / Littelfuse ACS LPSJ 60A 2 POLE ASSEMBLY KIT</p>	 <p><b>US681-C00005-500PG</b> Measurement Specialties / TE Connectivity SENSOR 500PSIG 1/4NPT 4-20MA 2'</p>
 <p><b>US6J11</b> ROHM US6J11 ROHM</p>	 <p><b>US6J2</b> ROHM US6J2 ROHM</p>	 <p><b>US6J2TR</b> LAPIS Semiconductor MOSFET 2P-CH 20V 1A TUMT6</p>	 <p><b>US6J12 TCR</b> LAPIS Semiconductor US6J12 TCR ROHM</p>

### Hot Parts

More

- |                          |                      |                  |                   |                           |
|--------------------------|----------------------|------------------|-------------------|---------------------------|
| ⊛ 04025A1R8CAT2A         | ↔ 08053G104ZAT2A     | ⇒ 12065C103JAT9A | D 1206GA390JAT1A  | ⇒ 1808HA300KATME          |
| ⊣ ADP3293JCPZ-RL         | ⊛ ADW95136Z-02RL     | D AQS225R2SX     | ⇒ BL9193-25BAPRN  | ⇒ BSM100GAL120DN2K        |
| ⊛ DBS700B24              | ⊣ DCX51-16-13        | ⊛ DS1868S-100+TR | ↔ DS2703U+        | ⇒ FQPF5N60C               |
| D GDZ8V2BLP3             | ⊛ GRM32ER71C226KE18L | ⊣ ISL6440IAZ     | ⊛ IXFN120N10      | ⇒ LTC6652AHMS8-1.25#TRPBF |
| ⇒ MAX8882EUTJJ-T         | ↔ MBRB2060CT         | ⊛ MC79M05BT      | ⊣ NCV1117DT33T5G  | ⇒ PJ1084CM-3.3V           |
| ↔ PL611S-02-D73TC-R      | ⇒ RIAQ16TTEB2002FHD  | D RN1906FE       | ⊛ S-93C76ADFJ-TBK | ⊣ SBL3040PT               |
| ⊛ SC6600M3-265G          | D SKN2F50/18         | ⇒ SL04-M3-08     | ↔ SP8K22GTB1      | ⇒ SSIN3060                |
| ⊣ SST39VF6401B-70-4I-EKE | ⊛ STB15N65M5         | ↔ T2035H-600TRG  | ⇒ T250F1000EBN    | ⇒ T2709N04TOF             |
| ⊛ TLC252CDR              | ⊣ US6K41FRA          | ⊛ US6M11TR       | D US6M2GTR        | ⇒ US6M2GTR                |
| ↔ US6U37TR               | ⊛ VE-JT3-EX          | ⊣ VI-J42-CW      | ⊛ VUO80-14NO3     | ⇒ W0628SA100SAC           |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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